



DMP6023LFG

60V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
-60V	25mΩ @ V _{GS} = -10V	-7.7A		
-007	33mΩ @ V _{GS} = -4.5V	-6.8A		

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

POWERDI3333-8

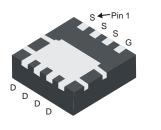
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

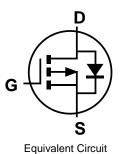
Mechanical Data

- Case: POWERDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



Bottom View





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Ordering Information (Note 4)

Part Number	Case	Packaging
DMP6023LFG-7	POWERDI3333-8	2,000/Tape & Reel
DMP6023LFG-13	POWERDI3333-8	3,000/Tape & Reel

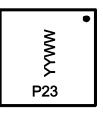
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P23= Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 13 = 2013) WW = Week Code (01 ~ 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-60	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note C) // 10//	Steady State	T _A = +25°C T _A = +70°C	۱ _D	-7.7 -6.2	А
Continuous Drain Current (Note 6) $V_{GS} = -10V$	t<10s	T _A = +25°C T _A = +70°C	ID	-10.3 -8.2	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-55	А		
Maximum Continuous Body Diode Forward Current	Is	-2.2	А		
Avalanche Current, L = 0.1mH			I _{AS}	-35.5	А
Avalanche Energy, L = 0.1mH			E _{AS}	62.9	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)		PD	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Р	123	°C/W
memai Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	69	
Total Power Dissipation (Note 6)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	60	°C/W
	t<10s	$R_{ heta JA}$	34	
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	6.3		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	—	—	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	—	—	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1	—	-3	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	р	—	—	25	mΩ	$V_{GS} = -10V, I_D = -5A$	
	R _{DS (ON)}		-	33	11152	$V_{GS} = -4.5V, I_D = -4A$	
Diode Forward Voltage	V _{SD}	—	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	2569		pF	$V_{DS} = -30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	C _{oss}	—	179		pF		
Reverse Transfer Capacitance	Crss	—	143	—	pF	1 - 110112	
Gate Resistance	R _g	_	8	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V,)	Qg	_	26.5	_	nC		
Total Gate Charge (V _{GS} = -10V),	Qg	_	53.1	-	nC		
Gate-Source Charge	Q _{gs}	—	7.1	_	nC	$V_{DS} = -30V, I_D = -5A$	
Gate-Drain Charge	Q _{gd}	—	12.6	_	nC		
Turn-On Delay Time	t _{D(on)}	_	6	_	ns		
Turn-On Rise Time	tr	_	7.1	_	ns	$V_{GS} = -10V, V_{DS} = -30V,$ $R_G = 3\Omega, I_D = -5A$	
Turn-Off Delay Time	t _{D(off)}	_	110	_	ns		
Turn-Off Fall Time	t _f	_	62		ns		
Body Diode Reverse Recovery Time	t _{rr}	_	20		ns	−I _F = -5A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	—	14	—	nC		

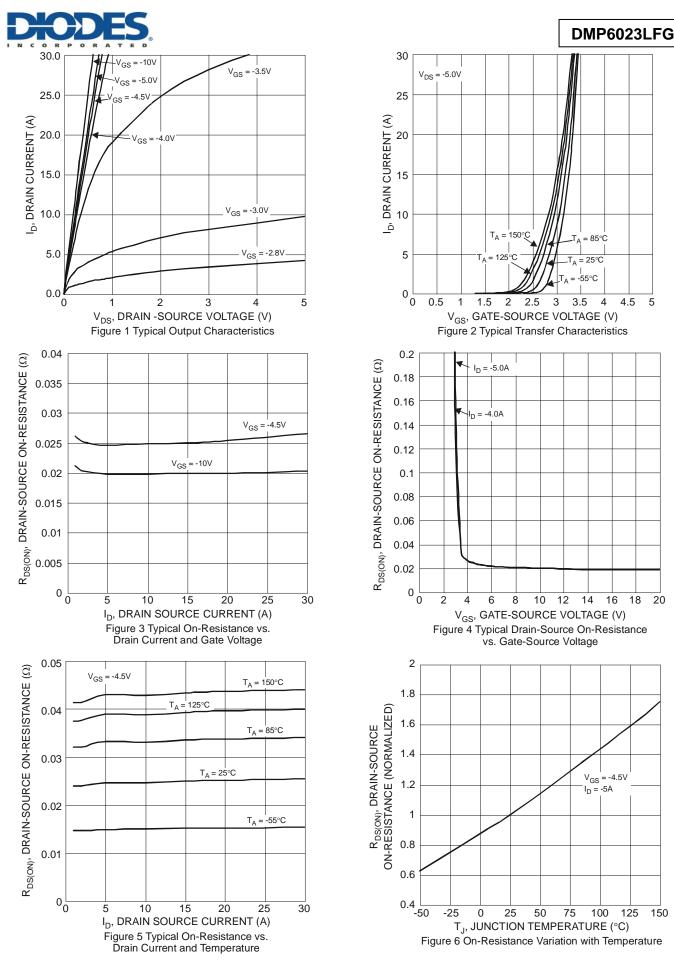
Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate
Short duration pulse test used to minimize self-heating effect.

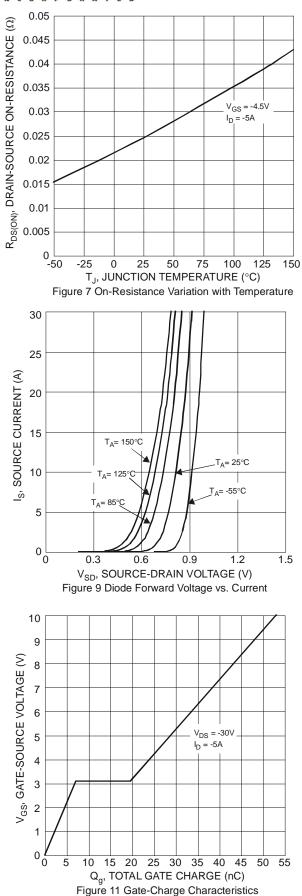
8. Guaranteed by design. Not subject to product testing.

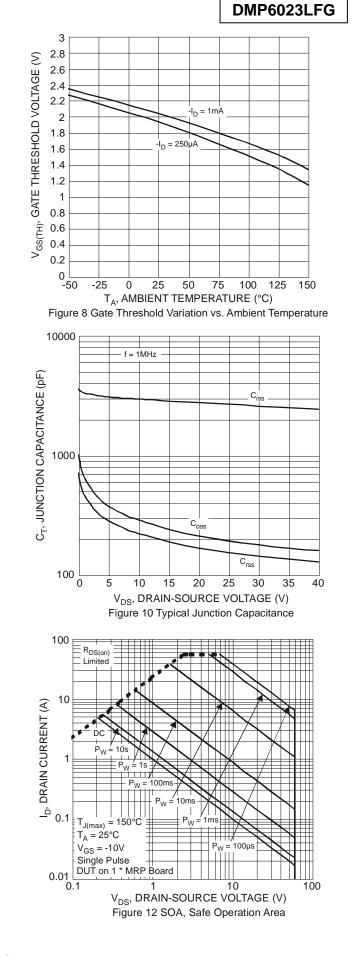
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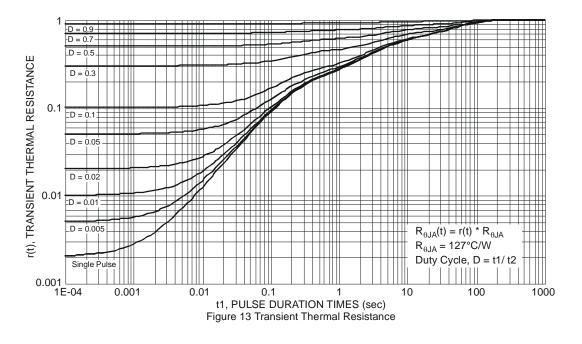






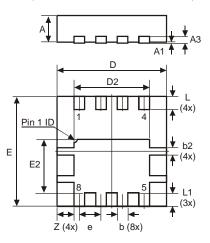






Package Outline Dimensions

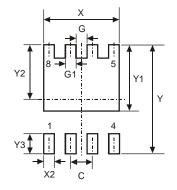
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



POWERDI [®] 3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
ш	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
L	0.35	0.45	0.40		
L1	_	-	0.39		
е	_	-	0.65		
Z	_	_	0.515		
All I	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
Х	2.370			
X2	0.420			



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